

W-Band Power Amplifier, 75 to 100 GHz, 25 dB Gain, +15 dBm P_{1dB}

Description:

SBP-7531042515-1010-E1-WP is a power amplifier with a typical small signal gain of 25 dB and a nominal output power of +15 dBm across the frequency range of 75 to 100 GHz. The DC power requirement for the amplifier is +15 $V_{DC}/350$ mA. The mechanical configuration offers an in line structure with WR-10 waveguides and UG-387/U-M anti-cocking flanges. Other port configurations, such as with 1 mm connectors or a right angle structure with WR-



10 waveguides, are also available under different model numbers.

Features:

- Full Waveguide Band Coverage
- High Gain
- High Output Power

Applications:

- Radar Systems
- Communication Systems
- Test Equipment

Electrical Specifications:

Parameter	Minimum	Typical	Maximum
Frequency	75 GHz		100 GHz
Gain		25 dB	
P_{1dB}		+15 dBm	
P _{sat}		+20 dBm	
P _{in}			+15 dBm
Input Return Loss		10 dB	
Output Return Loss		8 dB	
DC Voltage	+13 V _{DC}	+15 V _{DC}	+16 V _{DC}
DC Supply Current		350 mA	
Specification Temperature		+25 °C	
Operating Temperature	0 °C	The same of the sa	+50 °C

Mechanical Specifications:

Item	Item Specification	
Input Port	WR-10 Waveguide with UG-387/U-M Anti-Cocking Flange	
Output Port	WR-10 Waveguide with UG-387/U-M Anti-Cocking Flange	
Bias	Solder Pin	
Case Material	Aluminum	
Finish	Gold Plated	
Weight	1.6 Oz	
Size	1.10" (W) X 1.50" (L) X 0.75" (H)	
Outline	BG-SW-2-A	



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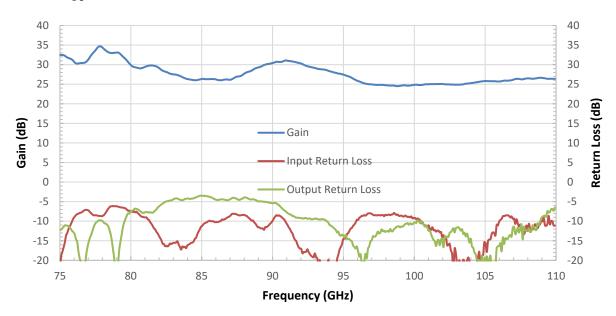
SAGE Millimeter, Inc.

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Test Data:

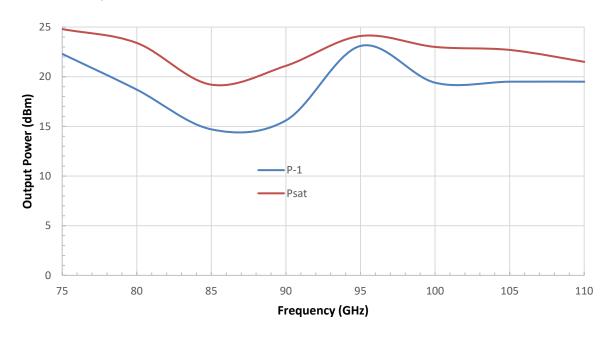
Gain and Return Loss vs. Frequency

Bias: +15 V_{DC}/348 mA



Output Power vs. Frequency

Bias: $+15 V_{DC}/348 \text{ mA}$ RFsat: +15 Vdc/480 mA





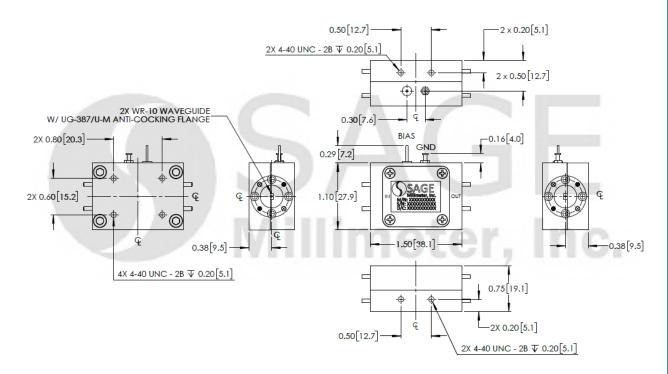
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Mechanical Outline: (Unless otherwise specified, all dimensions are in inches [millimeters])



Note:

- All data presented is collected from a sample lot. Actual data may vary unit to unit.
- All testing was performed under +25 °C case temperature.
- Eravant reserves the right to change the information presented without notice.
- Other mechanical configurations are available under different model numbers.

Caution:

- Exceeding absolute maximum ratings shown will damage the device.
- The device is static sensitive. Always follow ESD rules when working with the device.
- The case temperature of the device shall never exceed +50 °C. Use proper heatsink or fan if necessary.
- Any foreign objects in the waveguide will cause performance degradation and may damage the device.





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